

Document information

| Info | Content |
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| Keywords | BLF888A, DVB-T, UHF broadcast |
| Abstract | This application note describes the design and performance of a DVB-T UHF power amplifier using the BLF888A. |

Revision history

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| AN11062#2 | 20150901 | Modifications <ul style="list-style-type: none">• The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.• Legal texts have been adapted to the new company name where appropriate. |
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1. Introduction

For the past few years, new product design in the broadcast industry has been dominated by emerging digital modulation standards. A specific example is broadcast television, where many new transmitter systems are currently being set up as part of the conversion to digital terrestrial television.

The BLF888A is a UHF LDMOS power transistor intended for the broadcast transmitter market. The BLF888A can deliver 110 W DVB-T average power over the full UHF band from 470 MHz to 860 MHz at a CCDF of 8 dB (0.01 % probability). Higher average DVB-T power (120 W average) is possible depending on required linearity and predistorter capabilities. The transistor is also capable of handling analog TV (ATV) signals. The average power delivered will be dependent on cooling conditions.

Today, UHF transmitter design focuses on increasing efficiency and output power, while reducing size. To achieve these goals, the next generation of UHF transistors must deliver greater power levels, increased efficiency and higher gain, and the size of application boards needs to be reduced. The BLF888A meets these requirements. The BLF888A has been optimized for extreme low thermal resistance ($R_{th(j-c)} = 0.15 \text{ K/W}$) and improved ruggedness ($> 40 : 1$ at 860 MHz).

This report describes a broadband application incorporating the BLF888A, built on a small form factor board with a total size of 105 mm × 50 mm.

2. Circuit description

The BLF888A broadband application circuit is shown in [Figure 1](#). It is a Class AB common source amplifier. Circuit dimensions are 105 mm × 50 mm (including the transistor). If the connectors are excluded, the dimensions are 95 mm × 50 mm. The PCB material is Taconic RF35 ($\epsilon_r = 3.5$) with a thickness of 0.76 mm.

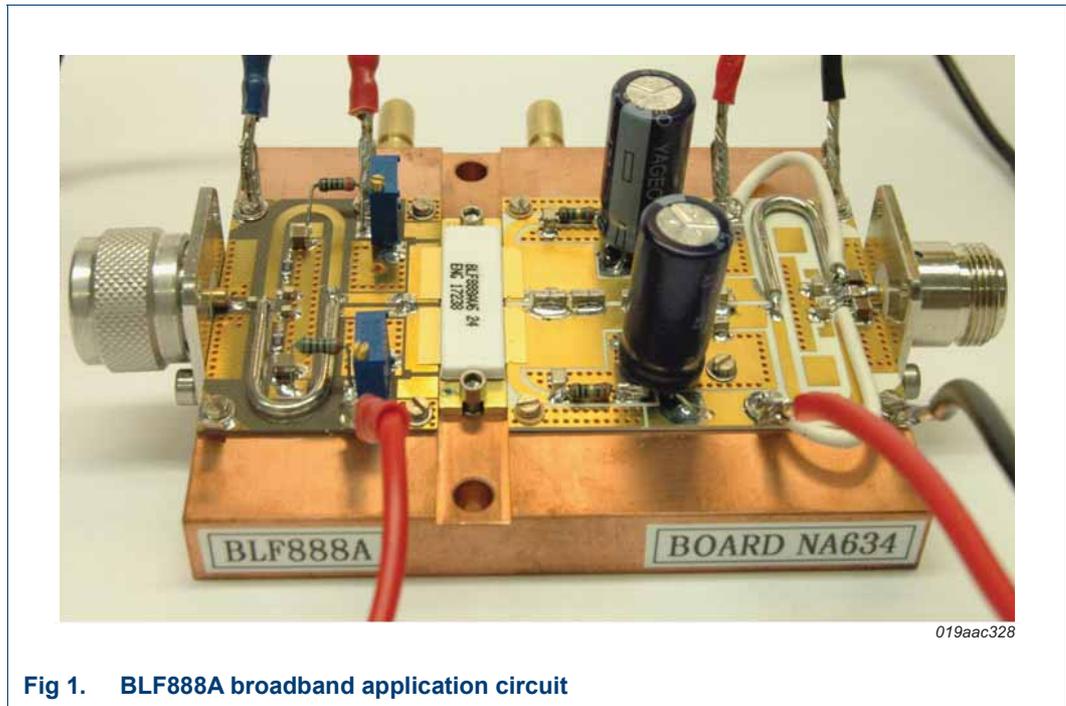


Fig 1. BLF888A broadband application circuit

A schematic diagram of the application design is shown in [Figure 2](#). The output consists of two microstrip lines per side, L1 and L2, and a balun B1 (25 Ω). C1 to C9 are used to match the transistor impedance to the input impedance of the balun (25 Ω). The balun converts the 25 Ω differential impedance to a 50 Ω asymmetrical impedance at the output. The length of the balun is approximately $\lambda/8$ at the UHF middle frequency. Microstrip line L3 is connected to the differential input of the balun to improve symmetry of the impedance to ground.

L5 in combination with C17 and C18 improves matching at the lower UHF frequencies. C11 and C12 influence the common mode impedance and improve the harmonic behavior. R1 and R2 were added for low frequency damping.

The input also consists of two microstrip lines, L30 and L31, and a balun B2 (25 Ω). C34 and C35 are RF decoupling capacitors for the balun. The transistor gate supply is connected via an RC network consisting of resistors R3 to R6, along with C36 and C37. This RC network performs a damping function that helps improve stability. Microstrip line L32 performs the same function at the input as microstrip line L3 at the output.

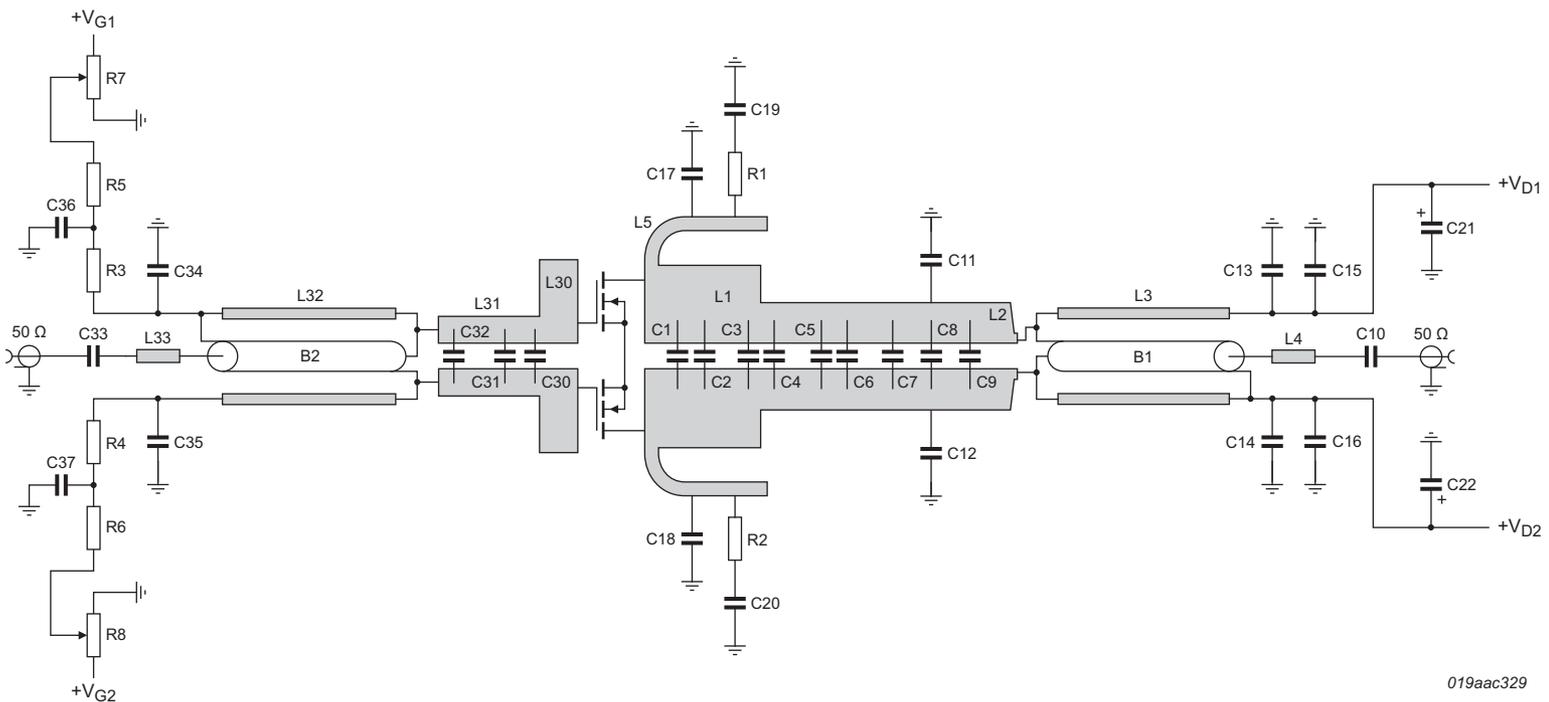


Fig 2. Class-AB common-source broadband amplifier

3. Design and Simulation

3.1 BLF888A impedance and simulation data

The impedance data detailed in [Figure 3](#) and [Figure 4](#) was used as a starting point in the development of the broadband circuit. This data is simulated from the equivalent circuit of the transistor. By using the equivalent circuit, impedances can be simulated from the internal drain current source and gate capacitance.

The push-pull and common mode simulation results for the broadband application circuit are shown in [Figure 6](#) and [Figure 7](#) respectively. The (common mode) low impedance in the second harmonic band (940 MHz to 1720 MHz) is of particular significance in the simulation. The resonance peaks in common mode can be shifted via capacitors C11 and C12 (see [Figure 2](#)). A high second harmonic impedance will result in significant power and efficiency losses.

3.1.1 Impedance data

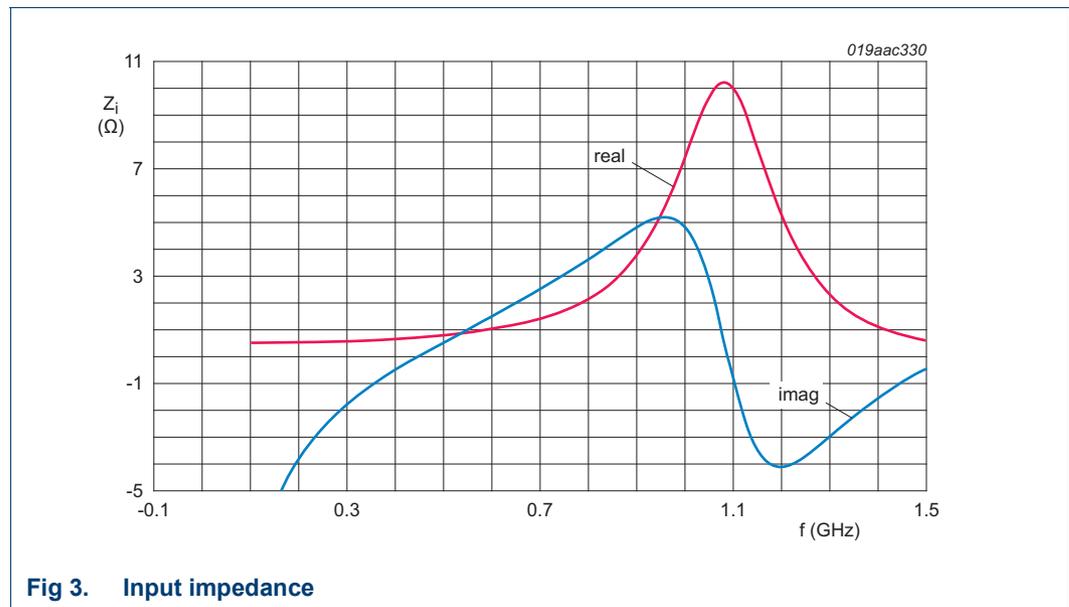


Fig 3. Input impedance

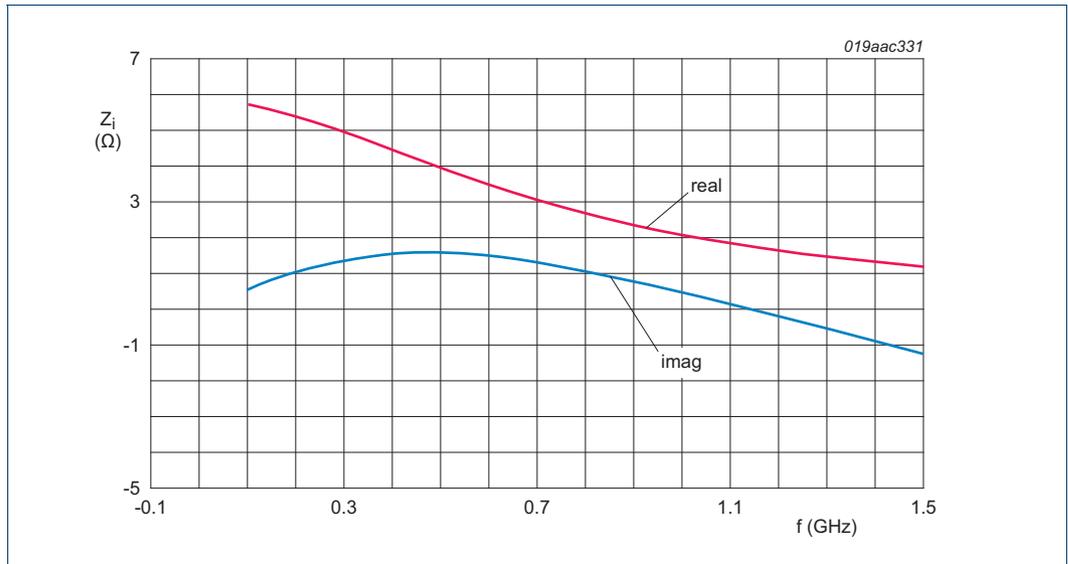


Fig 4. Output impedance; $P_O = 110\text{ W DVB-T (total device)}$

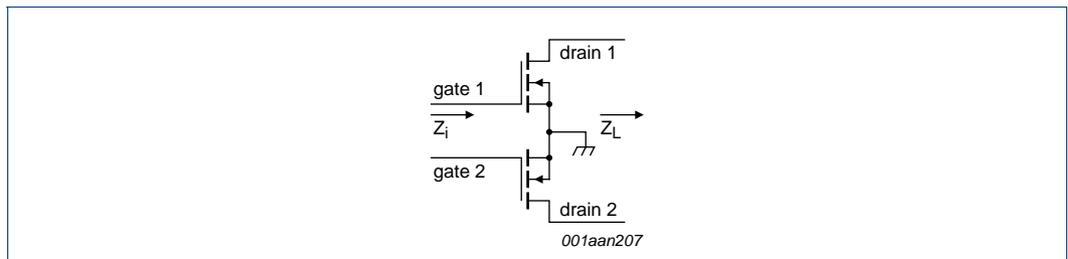
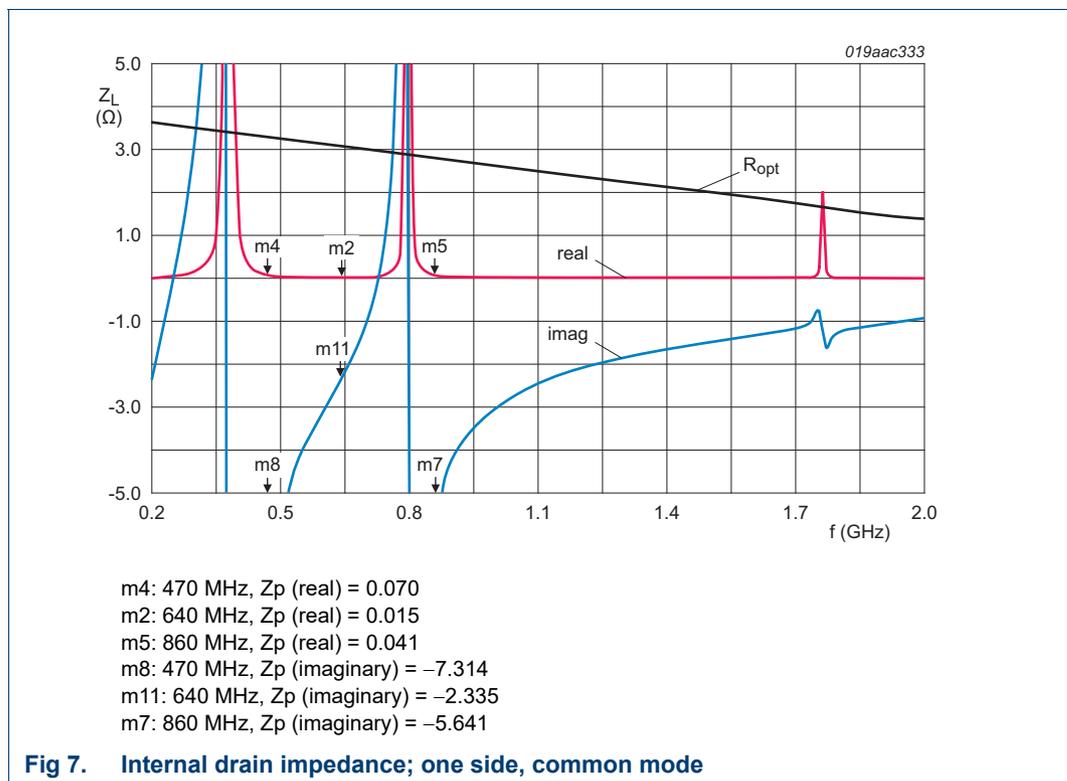
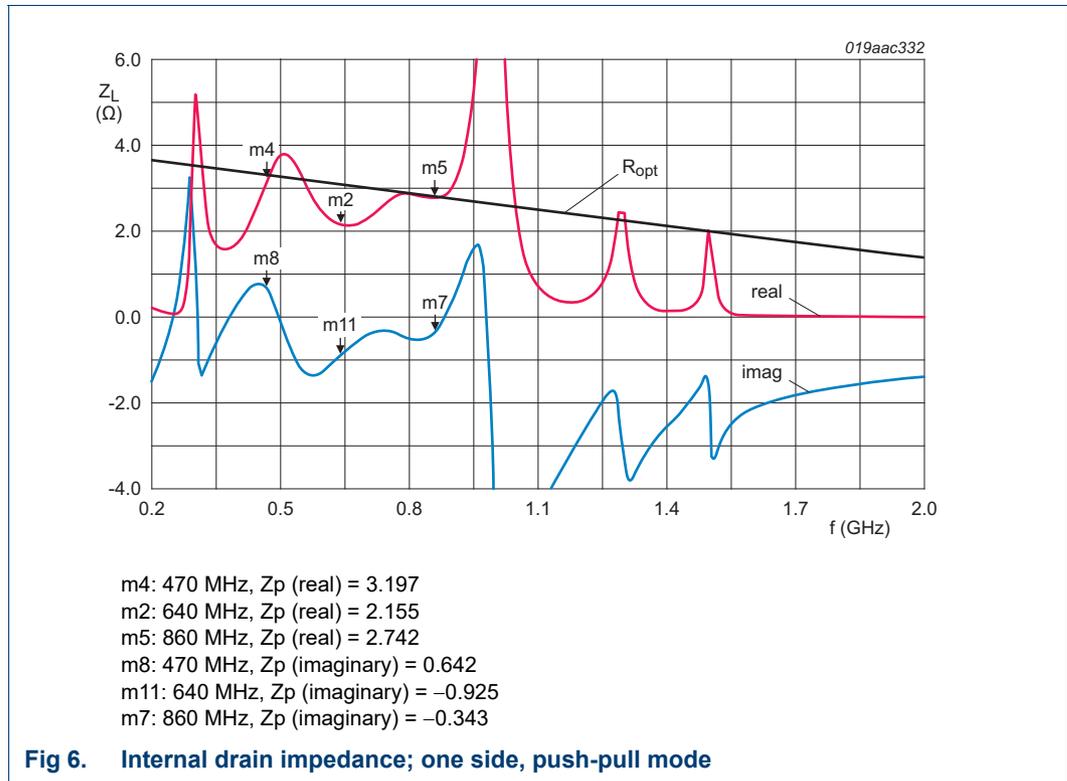


Fig 5. Definition of transistor impedance: $Z_i = \text{input impedance}$, $Z_L = \text{load impedance}$

3.1.2 Simulation data



3.2 Bias and decoupling circuit

The RF amplifier is sensitive to oscillations during mismatch. Therefore special care was taken to ensure adequate low frequency clamping at both the input and at the output. Two clamping resistors, R1 and R2, were added at the output for this purpose. Also, the supply is connected to the balun at the output. At the input, clamping is achieved via the RC network connected to the balun.

3.3 Thermal considerations

The circuit is designed to deliver 110 W DVB-T average power. The transistor can also handle CW, 2-tone and analog TV signals. However the power dissipation and heat generated by the transistor and the circuit can be excessively high, especially with CW and analog TV signals. The maximum junction temperature of the transistor is 200 °C. The electromagnetic (see [Ref. 1](#)) and lifetime (20 years minimum) restrictions must also be respected.

In this circuit, power dissipation is limited by the matching capacitors C1 and C2, and the balun ($P_{\max} = 150$ W (average)). For short-term testing, the circuit can handle CW power levels up to 450 W.

4. Test results

4.1 Large signal measurements

The test circuit was evaluated for DVB-T (110 W to 130 W average), 2-tone (250 W average) and pulsed CW. Besides the standard tests, special measurements were added with V_{DS} variation (46 V to 50 V) and water temperature variation (20 °C to 60 °C)

The demo circuit has a soldered transistor. This gives the best RF performance. A comparison is shown between a soldered and a clamped transistor.

The measurement results are shown in [Figure 8](#) to [Figure 13](#). All measurements were taken at $V_{DD} = 50$ V, $I_{Dq} = 1.3$ A (except for the V_{DS} variation) and $T_{\text{water}} = 20$ °C (except for the $T_{\text{hs}}/T_{\text{water}}$ variation).

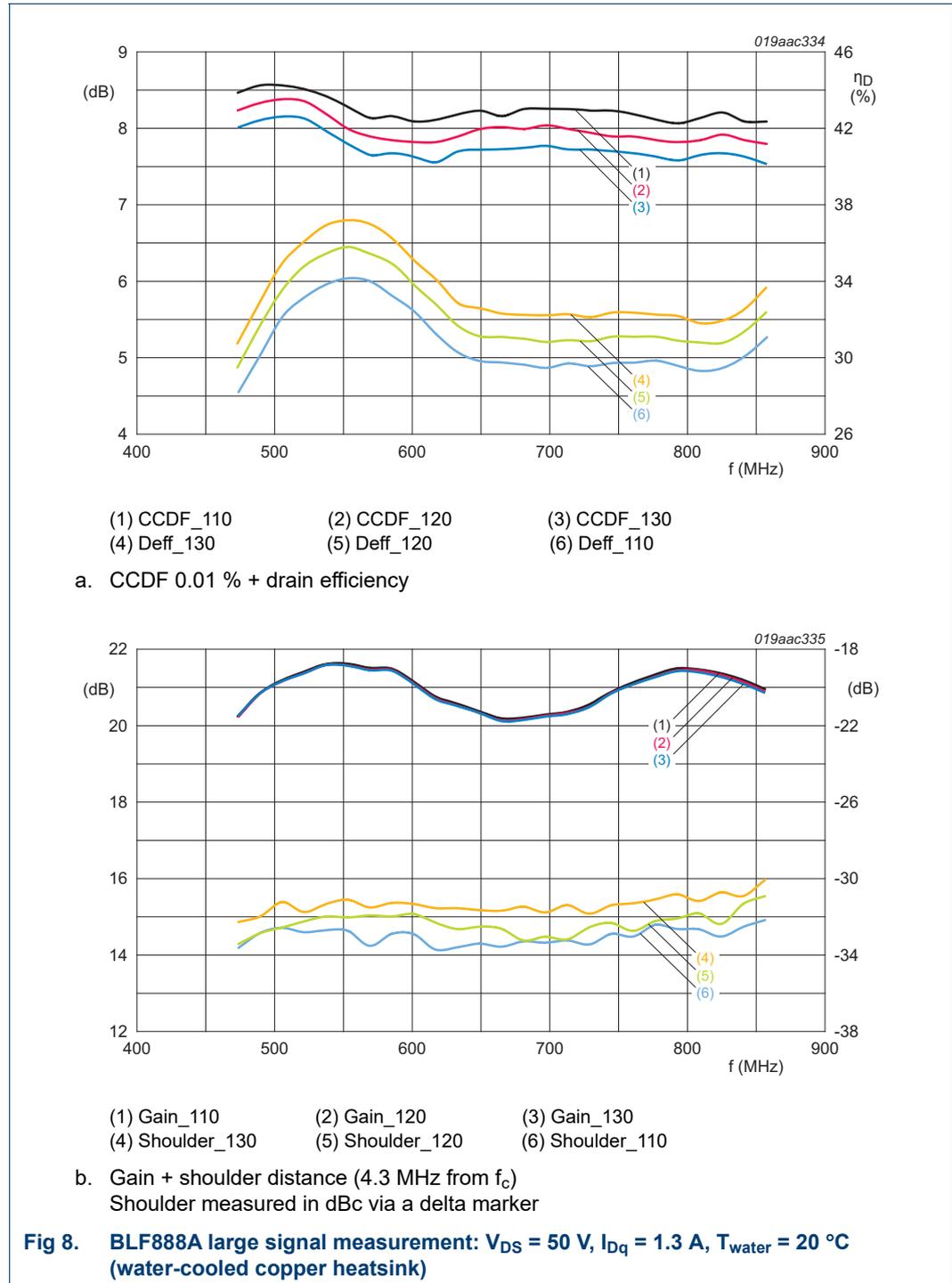
4.1.1 DVB-T

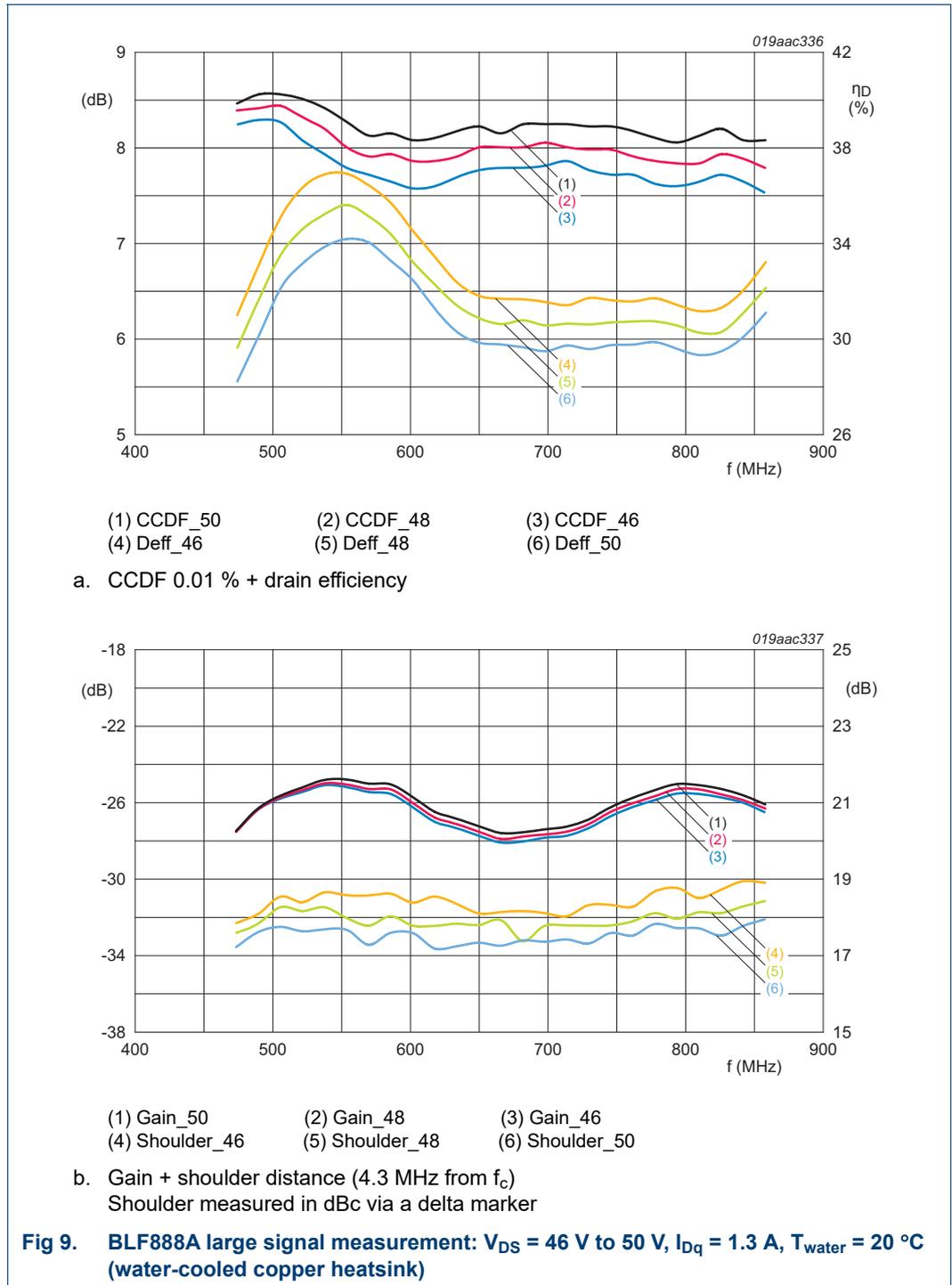
The target for the broadband circuit was to achieve average output power ($P_{L(AV)}$) of 110 W with a Peak-to-Average power Ratio (PAR) of 8 dB at a CCDF of 0.01 %. This target was met over the entire frequency range from 470 MHz to 860 MHz. Lead contact and capacitor positioning were extremely important in ensuring the target was met at the critical higher UHF frequencies (above 800 MHz). Shoulder distance is less than -30 dB and gain is greater than 20 dB over the entire frequency band.

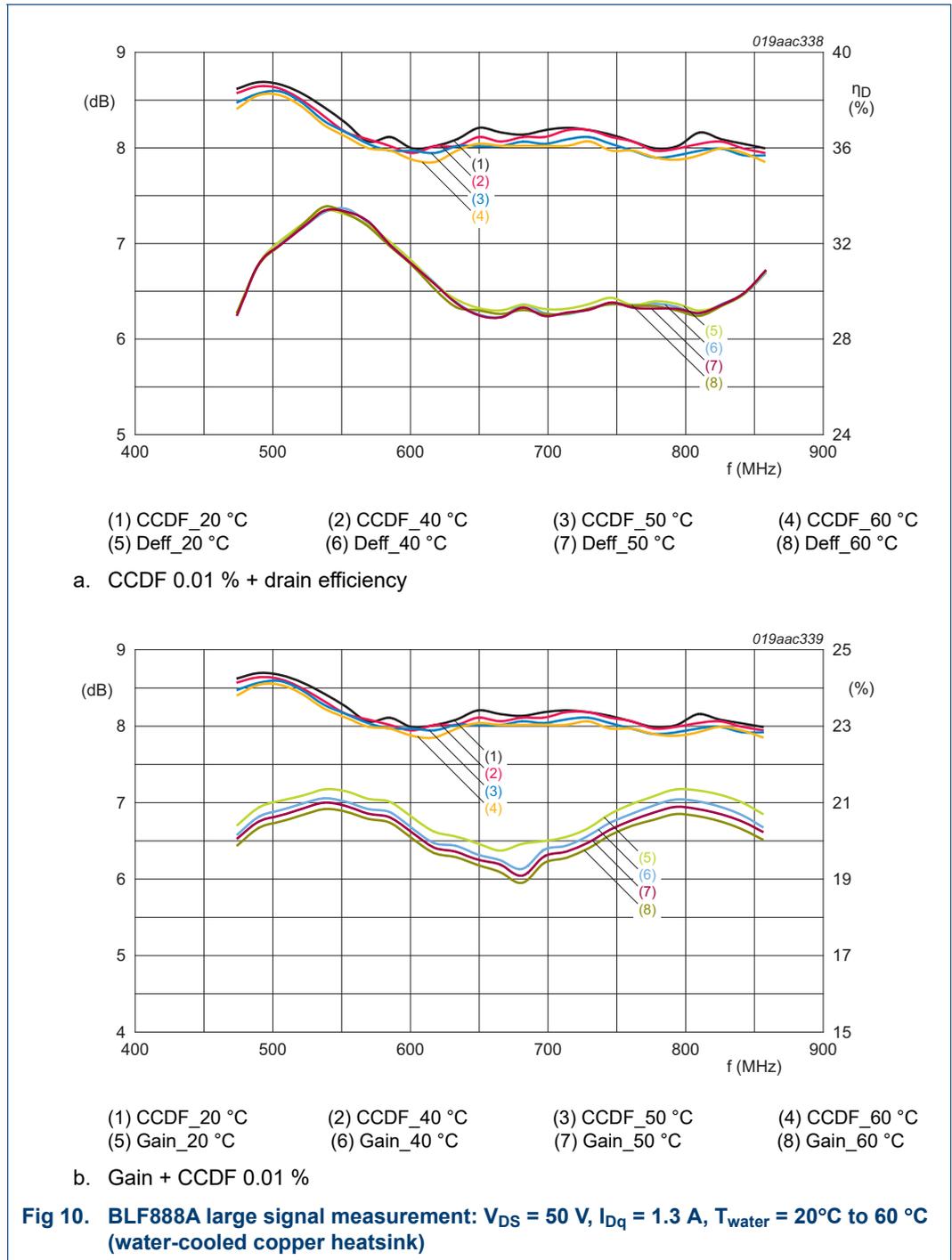
Drain efficiency (η_D) is greater than 28 % and is typically 30 % (at 110 W). Efficiency at the less responsive frequencies can be improved by lowering the supply voltage (the margin of the PAR at the less responsive frequencies in terms of η_D is wide enough to allow the supply voltage to be lowered).

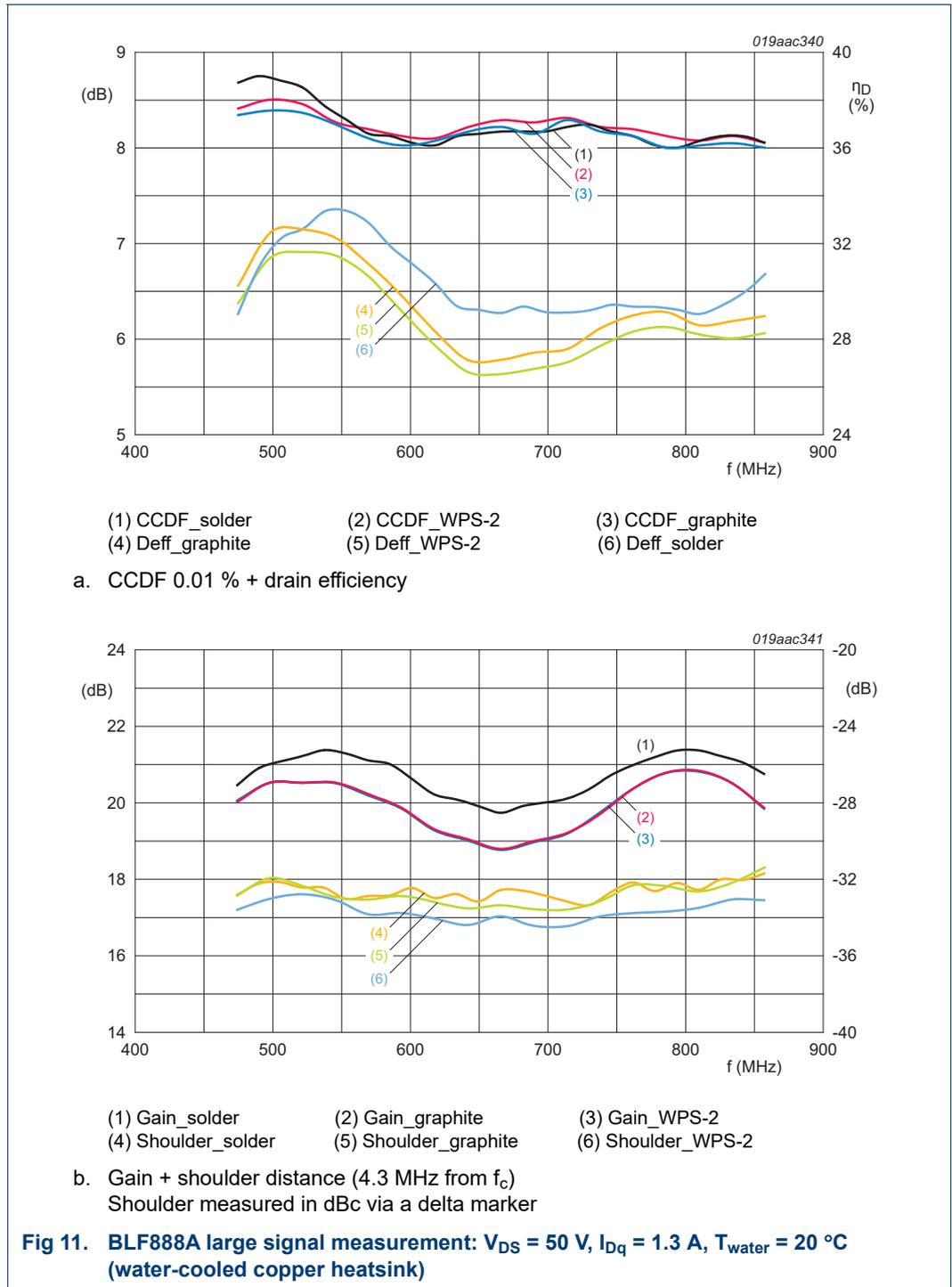
The influence of the cooling conditions (liquid cooled) can be seen in [Figure 11](#). The influence on CCDF / η_D is marginal in the measured range of T_{water} (20 °C to 60 °C). Gain will change by max. 1 dB.

Mounting has a significant effect on RF performance. This is shown in [Figure 12](#). Obviously best figures are achieved with a soldered transistor (CCDF / η_D). The comparison (soldered / clamped) was made with 2 different compounds: graphite (Fischer thermal transfer compound WLPG) and Austerlitz WPS-2 (without silicone). The graphite compound is electrically conducting and gives slightly better thermal / RF results.



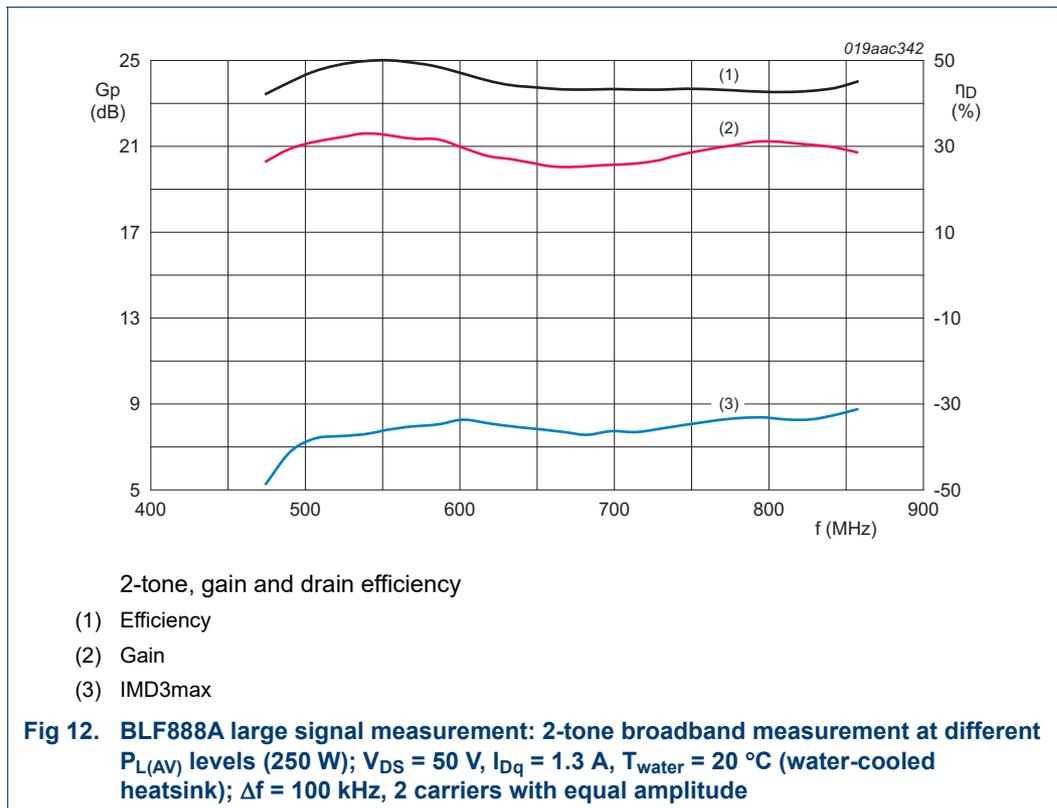






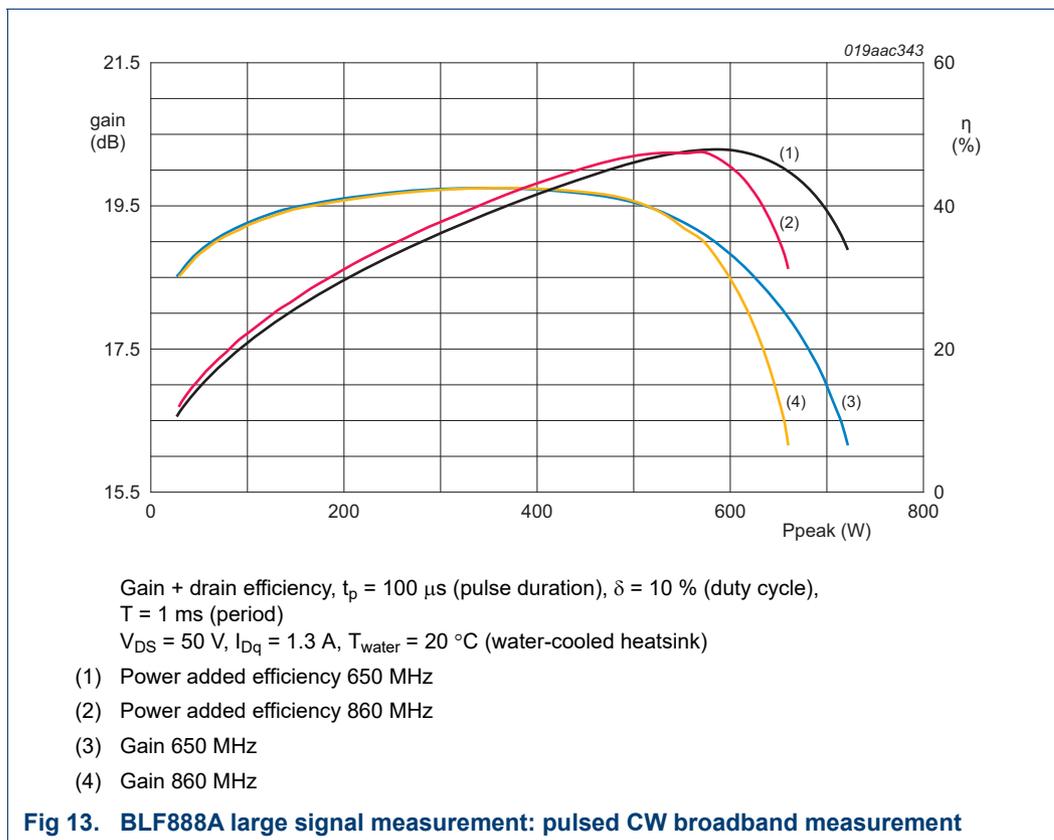
4.1.2 2-tone

Measurements were taken at $P_{L(AV)} = 250$ W (average). IMD3 levels are well below -30 dBc over the entire UHF frequency range. At these power levels, drain efficiency > 40 % and gain > 20 dB.



4.1.3 Pulsed

Pulsed measurement results between 470 MHz and 860 MHz (duty cycle = 10 %, $t_p = 100$ μ s) are shown in [Figure 13](#) (response at 650 MHz and 850 MHz). This provides a clear illustration of the peak power capability of transistor plus circuit. The lowest peak power level (≈ 600 W) occurs at 860 MHz (due to the longer pulse duration, this is lower than the peak power with DVB-T).



5. Conclusion

The BLF888A broadband application circuit presented in this report fulfils the following requirements:

- $P_{L(AV)}$ DVB-T > 110 W
- Efficiency > 28 % (typ. 30 %)
- Shoulder distance < -30 dBc (typ. -33 dBc)
- Gain > 20 dB (typ. 21 dB)

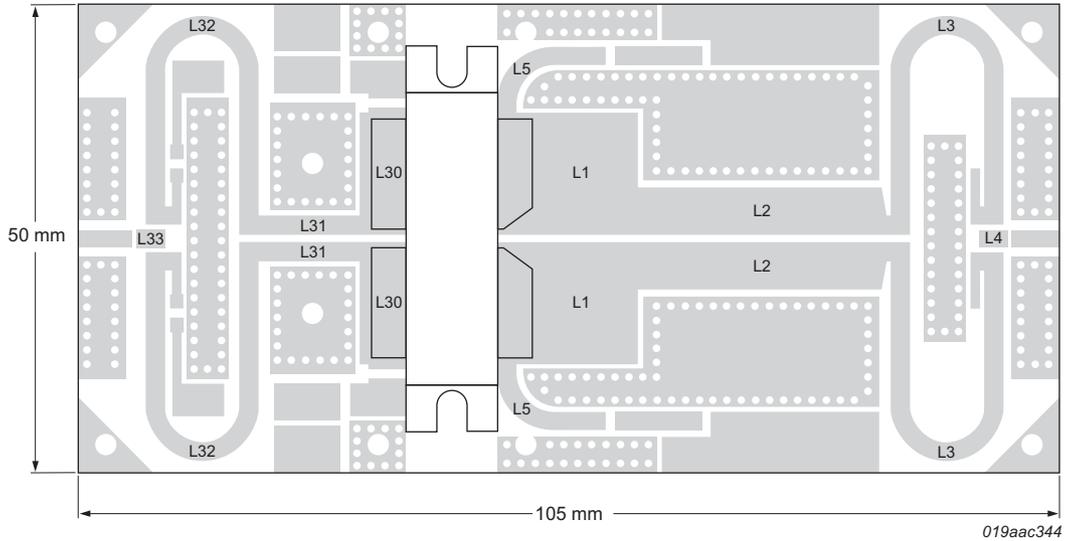
The circuit was designed for 110 W average DVB-T. The BLF888A is capable of delivering higher average power levels (e.g. in an ATV application). In such applications, special care must be taken to ensure adequate cooling is provided for the transistor and the circuit will need some redesign to handle the higher average power levels (e.g. the balun size).

The transistor has an extremely low R_{th} (0.15 K/W) which guarantees low junction temperatures and high reliability. It also enables the use of analog modulated TV signals.

Critical aspects of this broadband design include the harmonic loading (especially the 2nd harmonic of frequencies below 500 MHz), lead contact (an 'air gap' will shift the impedance level significantly) and low frequency stability (several damping resistors were added).

The transistor has an excellent ruggedness, with measured VSWR at 860 MHz > 40:1. Other frequencies show at least a VSWR >10:1.

6. Appendix A: PCB layout and Bill of Materials



See [Table 1](#) for a list of components.

All dimensions in mm; PCB input = 35 mm x 50 mm, PCB output = 60 mm x 50 mm, M2 holes

Fig 14. Dimensions of BLF888A broadband application circuit

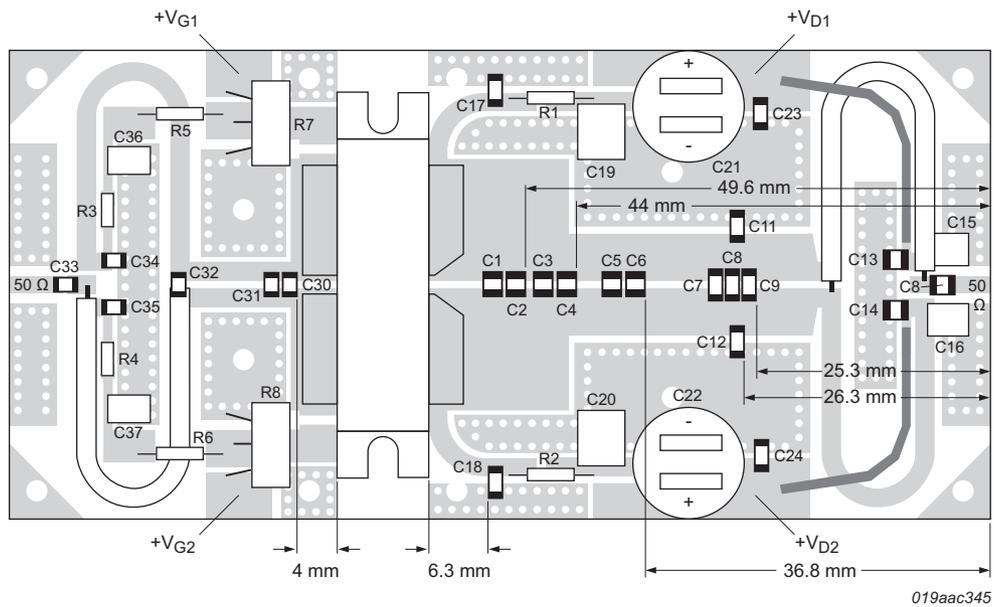


Fig 15. Component layout of BLF888A broadband application circuit

Table 1. Parts list for BLF888A broadband application circuit

| Component | Value | Type | Comment |
|--------------------|--|---|-----------------------|
| Output | | | |
| C1 | 12 pF | ATC180R | |
| C2, C3, C4, C5, C6 | 8.2 pF | ATC180R | |
| C7 | 6.8 pF | ATC100B | |
| C8 | 2.7 pF | ATC180R | |
| C9 | 2.2 pF | ATC100B | |
| C10, C13, C14 | 100 pF | ATC180R | |
| C11, C12 | 10 pF | ATC100B | |
| C17, C18, C23, C24 | 100 pF | ATC180B | |
| C15, C16 | 4.7 μ F | TDK C4532X7R1E475MT020U | 50 V |
| C19, C20 | 10 μ F | TDK C570X7R1H106KT000N | 50 V |
| C21, C22 | 470 μ F | electrolytic capacitor | 63 V |
| R1, R2 | 10 Ω | | |
| L1 | 15 mm \times 13 mm | microstrip line | length \times width |
| L2 | 26 mm \times 5 mm | microstrip line | length \times width |
| L3 | 49.5 mm \times 2 mm | microstrip line | length \times width |
| L4 | 3.5 mm \times 1.7 mm | microstrip line | length \times width |
| L5 | 9.5 mm \times 2 mm | microstrip line | length \times width |
| balun B1 | semi-rigid coax $Z_o = 25 \Omega$; 49.5 mm | UT-090C-25 (EZ 90-25) | |
| PCB | | Taconic RF35, $\epsilon_r = 3.5$ height = 0.76 mm; 50 mm \times 60 mm Cu plating 35 μ m | |
| Input | | | |
| C30 | 10 pF | ATC100A | |
| C31 | 9.1 pF | ATC100A | |
| C32 | 3.9 pF | ATC100A | |
| C33, C34, C35 | 100 pF | ATC100A | |
| C36, C37 | 4.7 μ F | TDK C4532X7R1E475MT020U | |
| R3, R4 | 5.6 Ω | | |
| R5, R6 | 100 Ω | | |
| R7, R8 | 1 k Ω | potentiometer | |
| L30 | 13 mm \times 5 mm | microstrip line | length \times width |
| L31 | 11 mm \times 2 mm | microstrip line | length \times width |
| L32 | 49.5 mm \times 2 mm | microstrip line | length \times width |
| L33 | 3 mm \times 2 mm | microstrip line | length \times width |
| balun B2 | semi-rigid coax $Z_o = 25 \Omega$; 49.5 mm | UT-090C-25 (EZ 90-25) | |

Table 1. Parts list for BLF888A broadband application circuit ...continued

| Component | Value | Type | Comment |
|-----------|-------|---|---------|
| PCB | | Taconic RF35, $\epsilon_r = 3.5$ h = 0.76 mm; 35 mm × 50 mm Cu plating 35 μm | |

7. Abbreviations

Table 2. Abbreviations

| Acronym | Description |
|---------|--|
| CCDF | Complementary Cumulative Distribution Function |
| DVB | Digital Video Broadcast |
| DVB-T | Digital Video Broadcast - Terrestrial |
| UHF | Ultra High Frequency |
| CW | Continuous Wave |
| IMD3 | Third-Order Intermodulation Distortion |
| PEP | Peak Envelope Power |

8. References

- [1] BLF888A data sheet

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